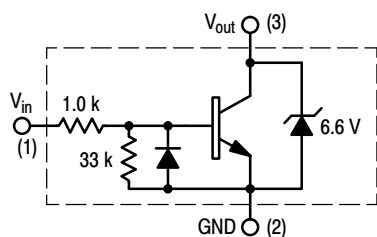
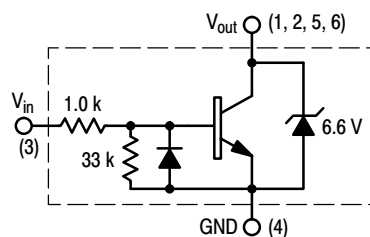


MDC3105

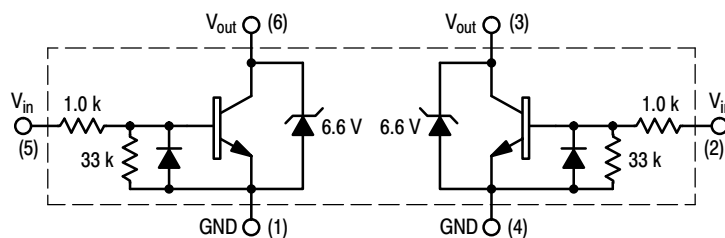
INTERNAL CIRCUIT DIAGRAMS



CASE 318



CASE 463A



CASE 318F

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Power Supply Voltage	V_{CC}	6.0	Vdc
Input Voltage	$V_{in(fwd)}$	6.0	Vdc
Reverse Input Voltage	$V_{in(rev)}$	-0.5	Vdc
Repetitive Pulse Zener Energy Limit (Duty Cycle $\leq 0.01\%$)	SOT-23 Ezpk	50	mJ
Output Sink Current – Continuous	I_O	500	mA
Junction Temperature	T_J	150	$^\circ\text{C}$
Operating Ambient Temperature Range	T_A	-40 to +85	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-65 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Total Device Power Dissipation (Note 1) Derate above 25°C	SOT-23 P_D	225 1.8	mW mW/ $^\circ\text{C}$
Total Device Power Dissipation (Note 1) Derate above 25°C	SC-74 P_D	380 1.5	mW mW/ $^\circ\text{C}$
Total Device Power Dissipation (Note 1) Derate above 25°C	SOT-563 P_D	357 2.9	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction-to-Ambient	SOT-23 SC-74 SOT-563 $R_{\theta JA}$	556 329 250	$^\circ\text{C}/\text{W}$

1. FR-5 PCB of $1'' \times 0.75'' \times 0.062''$, $T_A = 25^\circ\text{C}$

MDC3105

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Output Zener Breakdown Voltage (@ $I_T = 10\text{ mA}$ Pulse)	$V_{(BRout)}$ $V_{(-BRout)}$	6.2 –	6.6 –0.7	7.0 –	V V
Output Leakage Current @ 0 Input Voltage ($V_O = 5.5\text{ Vdc}$, $V_{in} = \text{O.C.}$, $T_A = 25^\circ\text{C}$) ($V_O = 5.5\text{ Vdc}$, $V_{in} = \text{O.C.}$, $T_A = 85^\circ\text{C}$)	I_{OO}	– –	– –	0.1 30	μA
Guaranteed "OFF" State Input Voltage ($I_O \leq 100\text{ }\mu\text{A}$)	$V_{in(off)}$	–	–	0.4	V

ON CHARACTERISTICS

Input Bias Current (H_{FE} Limited) ($I_O = 250\text{ mA}$, $V_O = 0.25\text{ Vdc}$)	I_{in}	–	0.8	1.6	mAdc
Output Saturation Voltage ($I_O = 250\text{ mA}$, $I_{in} = 1.5\text{ mA}$)	$V_{O(sat)}$	–	0.12	0.16	Vdc
Output Sink Current – Continuous ($V_{CE} = 0.25\text{ Vdc}$, $I_{in} = 1.5\text{ mA}$)	$I_{O(on)}$	250	400	–	mA

ORDERING INFORMATION

Device	Package	Shipping [†]
MDC3105LT1	SOT–23	3000 / Tape & Reel
MDC3105LT1G	SOT–23 (Pb–Free)	
MDC3105DMT1	SC–74	
MDC3105DMT1G	SC–74 (Pb–Free)	
MDC3105XV6T1G	SOT–563 (Pb–Free)	4000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL APPLICATION-DEPENDENT SWITCHING PERFORMANCE

SWITCHING CHARACTERISTICS

Characteristic	Symbol	Min	Typ	Max	Units
Propagation Delay Times:					nS
High to Low Propagation Delay; Figure 1 (5.0 V 74HC04)	t_{PHL}	–	55	–	
Low to High Propagation Delay; Figure 1 (5.0 V 74HC04)	t_{PLH}	–	430	–	
High to Low Propagation Delay; Figures 1, 13 (3.0 V 74HC04)	t_{PHL}	–	85	–	
Low to High Propagation Delay; Figures 1, 13 (3.0 V 74HC04)	t_{PLH}	–	315	–	
High to Low Propagation Delay; Figures 1, 14 (5.0 V 74LS04)	t_{PHL}	–	55	–	
Low to High Propagation Delay; Figures 1, 14 (5.0 V 74LS04)	t_{PLH}	–	2.4	–	μ S
Transition Times:					nS
Fall Time; Figure 1 (5.0 V 74HC04)	t_f	–	45	–	
Rise Time; Figure 1 (5.0 V 74HC04)	t_r	–	160	–	
Fall Time; Figures 1, 13 (3.0 V 74HC04)	t_f	–	70	–	
Rise Time; Figures 1, 13 (3.0 V 74HC04)	t_r	–	195	–	
Fall Time; Figures 1, 14 (5.0 V 74LS04)	t_f	–	45	–	
Rise Time; Figures 1, 14 (5.0 V 74LS04)	t_r	–	2.4	–	μ S

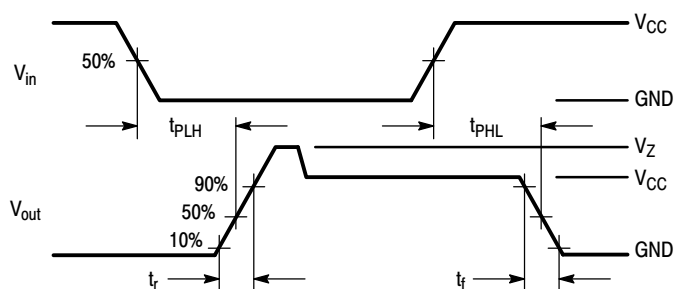


Figure 1. Switching Waveforms

TYPICAL PERFORMANCE CHARACTERISTICS (ON CHARACTERISTICS)

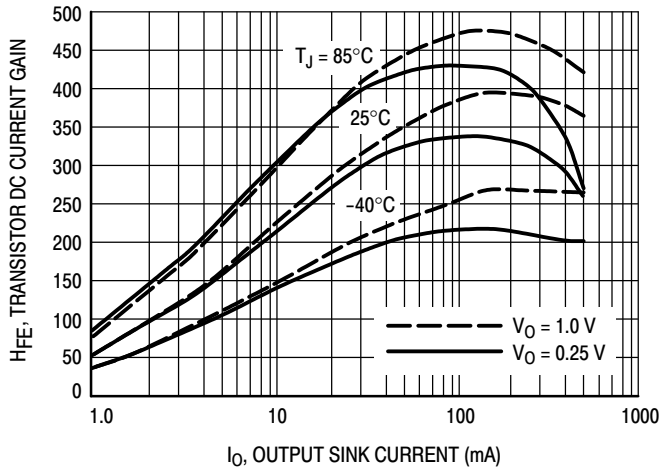


Figure 2. Transistor DC Current Gain

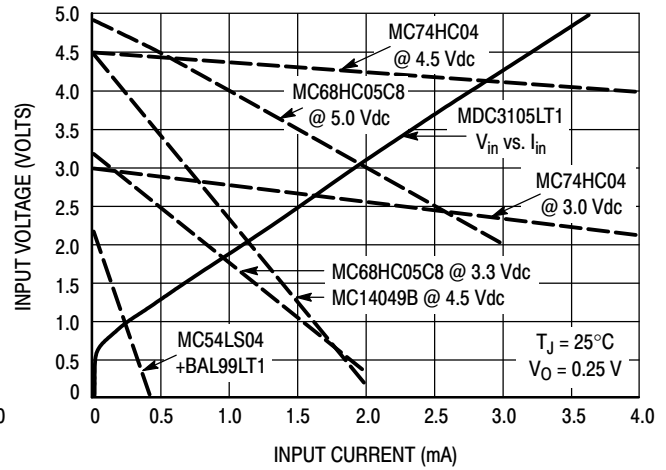


Figure 3. Input V-I Requirement Compared to Possible Source Logic Outputs

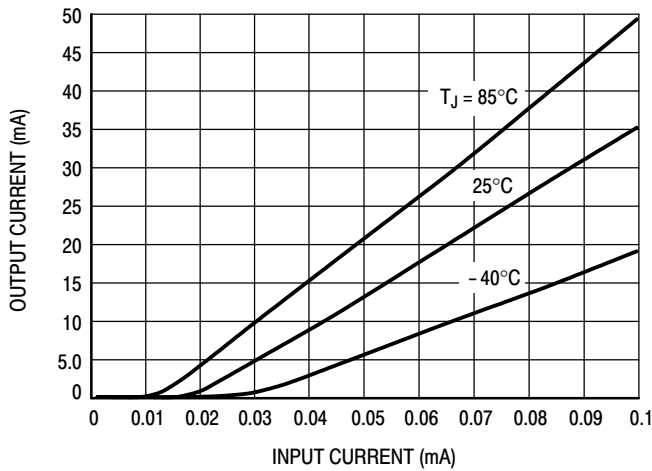


Figure 4. Threshold Effects

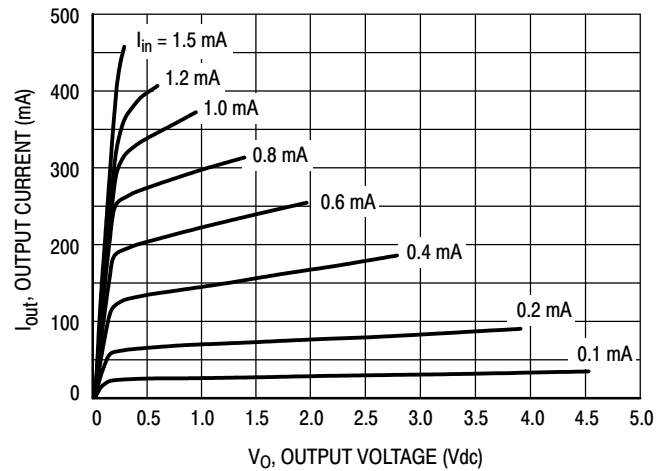


Figure 5. Transistor Output V-I Characteristic

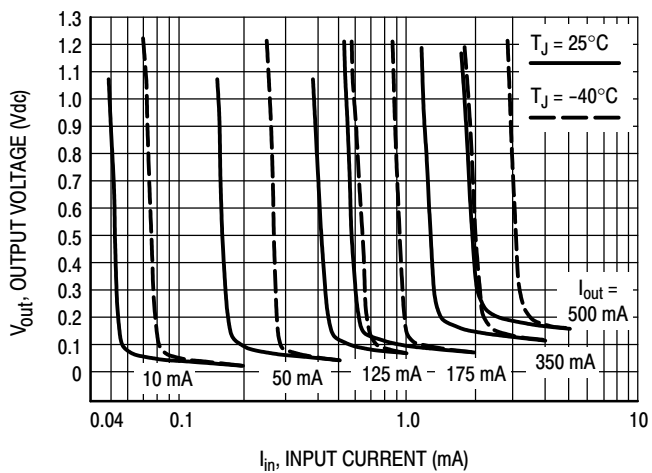


Figure 6. Output Saturation Voltage versus I_{out}/I_{in}

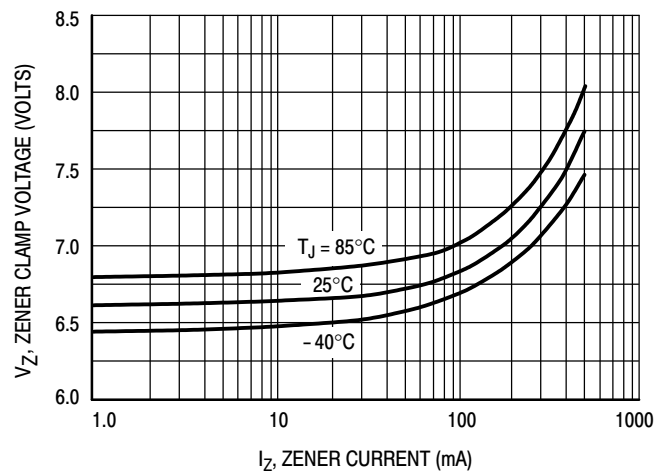


Figure 7. Zener Clamp Voltage versus Zener Current

TYPICAL PERFORMANCE CHARACTERISTICS
(OFF CHARACTERISTICS)

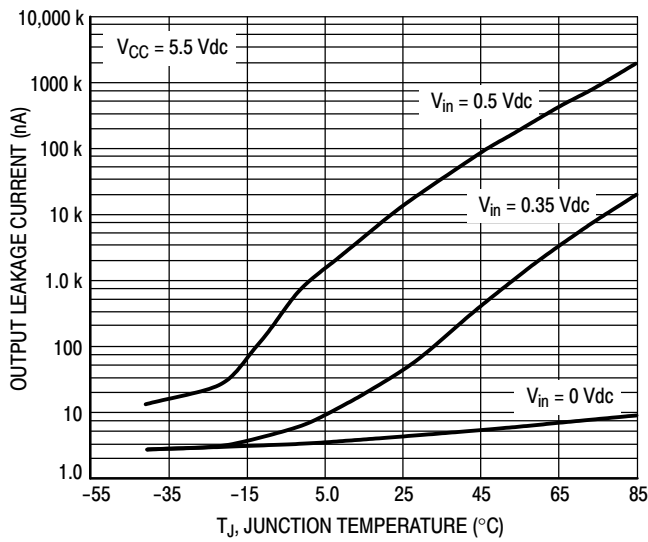


Figure 8. Output Leakage Current versus Temperature

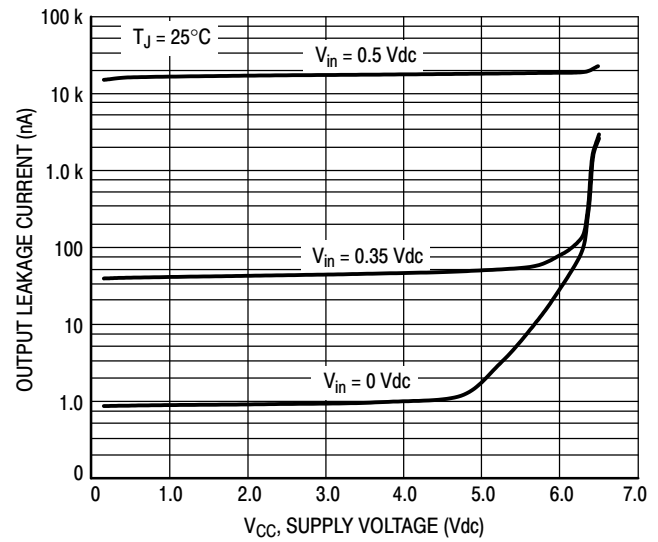


Figure 9. Output Leakage Current versus Supply Voltage

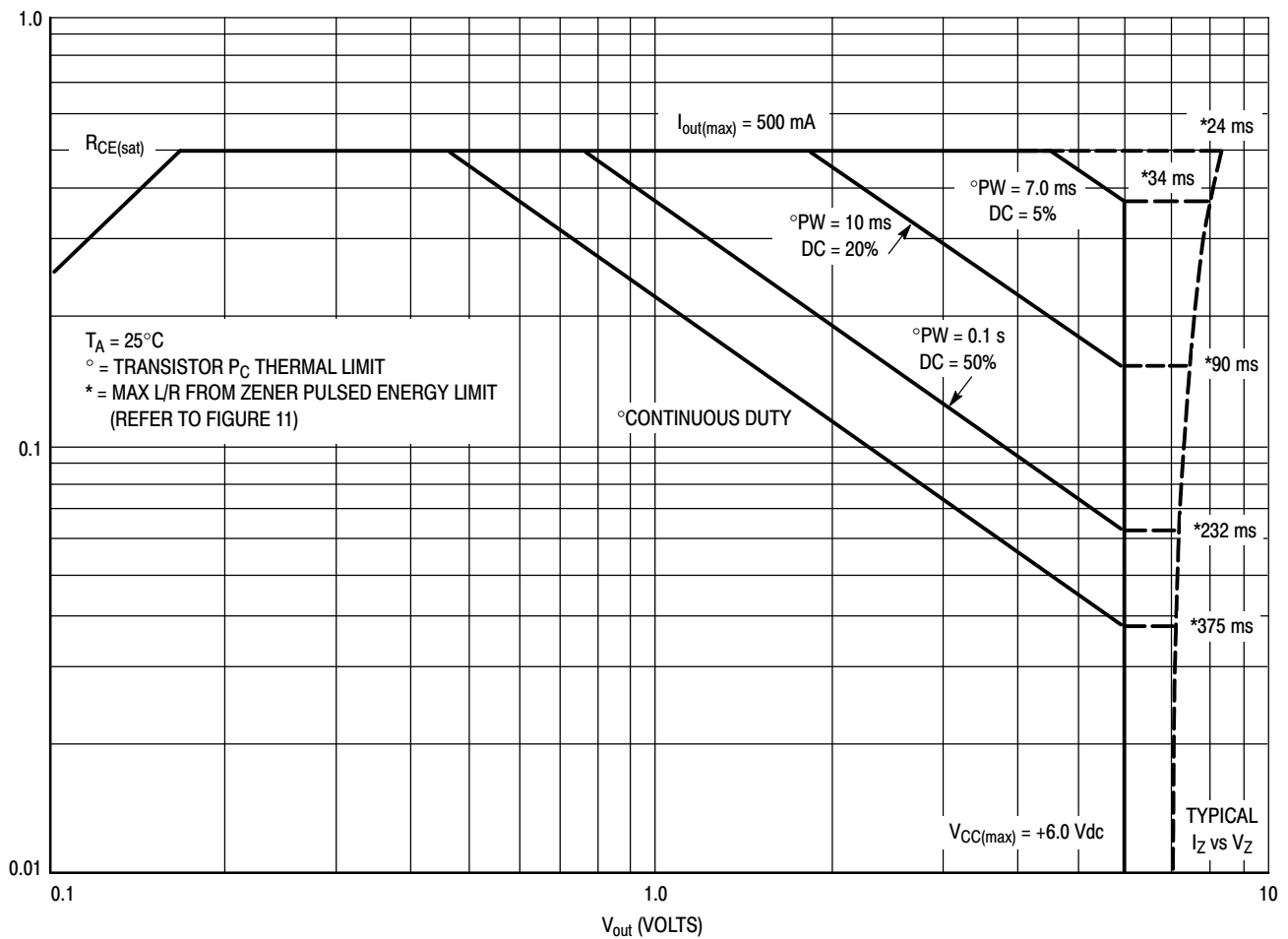


Figure 10. Safe Operating Area for MDC3105LT1

MDC3105

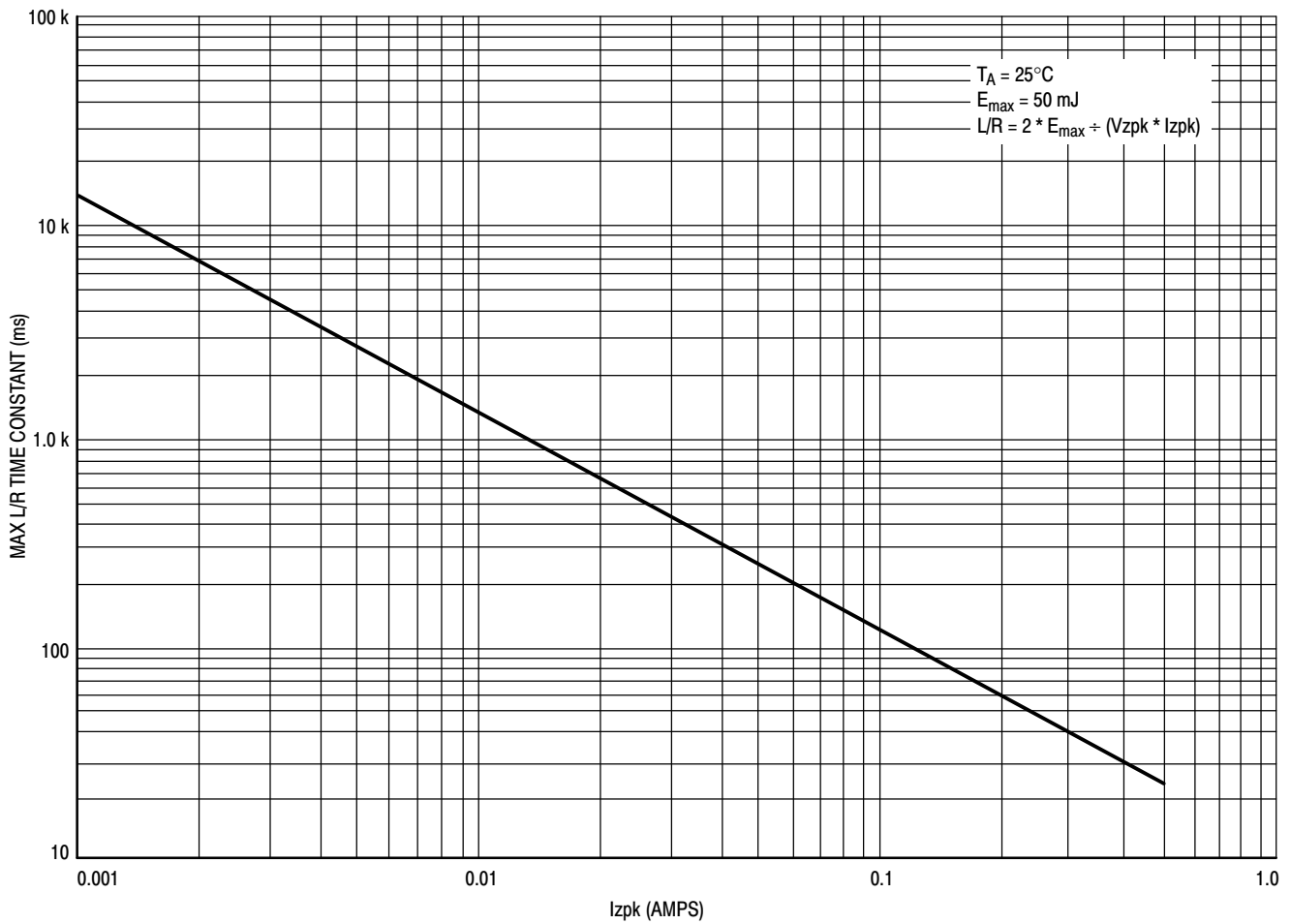


Figure 11. Zener Repetitive Pulse Energy Limit on L/R Time Constant for MDC3105LT1

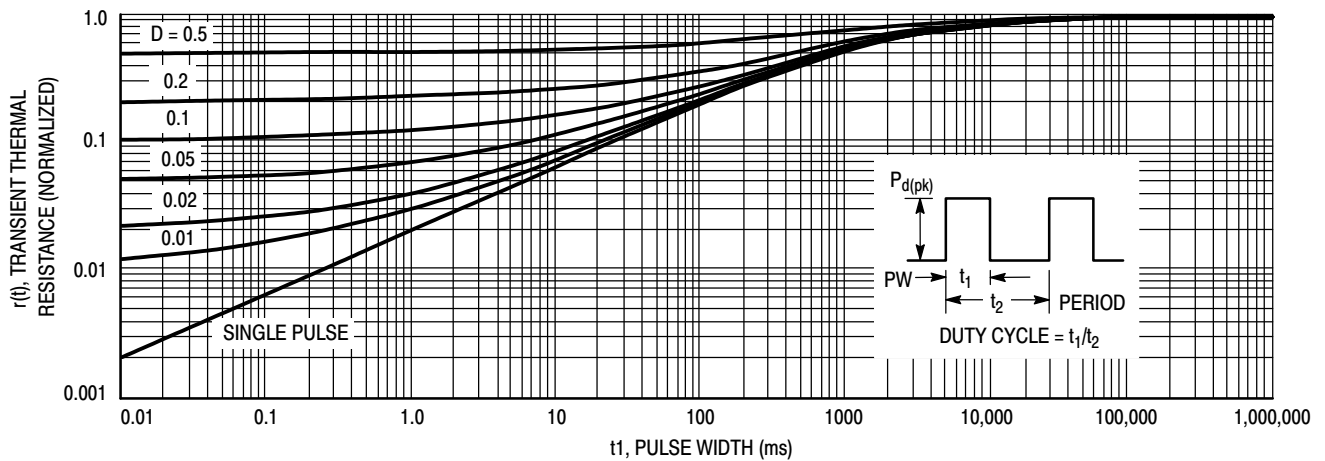


Figure 12. Transient Thermal Response for MDC3105LT1

Using TTR Designing for Pulsed Operation

For a repetitive pulse operating condition, time averaging allows one to increase a device's peak power dissipation rating above the average rating by dividing by the duty cycle of the repetitive pulse train. Thus, a continuous rating of 200 mW of dissipation is increased to 1.0 W peak for a 20% duty cycle pulse train. However, this only holds true for pulse widths which are short compared to the thermal time constant of the semiconductor device to which they are applied.

For pulse widths which are significant compared to the thermal time constant of the device, the peak operating condition begins to look more like a continuous duty operating condition over the time duration of the pulse. In these cases, the peak power dissipation rating cannot be merely time averaged by dividing the continuous power rating by the duty cycle of the pulse train. Instead, the average power rating can only be scaled up a reduced amount in accordance with the device's transient thermal response, so that the device's max junction temperature is not exceeded.

Figure 12 of the MDC3105 data sheet plots its transient thermal resistance, $r(t)$ as a function of pulse width in ms for various pulse train duty cycles as well as for a single pulse and illustrates this effect. For short pulse widths near the left side of the chart, $r(t)$, the factor, by which the continuous duty thermal resistance is multiplied to determine how much the peak power rating can be increased above the average power rating, approaches the duty cycle of the pulse train, which is the expected value. However, as the pulse width is increased, that factor eventually approaches 1.0 for all duty cycles indicating that the pulse width is sufficiently long to appear as a continuous duty condition to this device. For the MDC3105LT1, this pulse width is about 100 seconds. At this and larger pulse widths, the peak power dissipation capability is the same as the continuous duty power capability.

To use Figure 12 to determine the peak power rating for a specific application, enter the chart with the worst case pulse condition, that is the max pulse width and max duty cycle and determine the worst case $r(t)$ for your application. Then calculate the peak power dissipation allowed by using the equation,

$$Pd(pk) = (T_{Jmax} - T_{Amax}) \div (R_{\theta JA} * r(t))$$

$$Pd(pk) = (150^{\circ}C - T_{Amax}) \div (556^{\circ}C/W * r(t))$$

Thus for a 20% duty cycle and a PW = 40 ms, Figure 12 yields $r(t) = 0.3$ and when entered in the above equation, the max allowable $Pd(pk) = 390$ mW for a max $T_A = 85^{\circ}C$.

Also note that these calculations assume a rectangular pulse shape for which the rise and fall times are insignificant compared to the pulse width. If this is not the case in a specific application, then the V_O and I_O waveforms should be multiplied together and the resulting power waveform integrated to find the total dissipation across the device. This then would be the number that has to be less than or equal to the $Pd(pk)$ calculated above. A circuit simulator having a waveform calculator may prove very useful for this purpose.

Notes on SOA and Time Constant Limitations

Figure 10 is the Safe Operating Area (SOA) for the MDC3105. Device instantaneous operation should never be pushed beyond these limits. It shows the SOA for the Transistor "ON" condition as well as the SOA for the Zener during the turn-off transient. The max current is limited by the I_{zpk} capability of the Zener as well as the transistor in addition to the max input current through the resistor. It should not be exceeded at any temperature. The BJT power dissipation limits are shown for various pulse widths and duty cycles at an ambient temperature of $25^{\circ}C$. The voltage limit is the max V_{CC} that can be applied to the device. When the input to the device is switched off, the BJT "ON" current is instantaneously dumped into the Zener diode where it begins its exponential decay. The Zener clamp voltage is a function of that BJT current level as can be seen by the bowing of the V_Z versus I_Z curve at the higher currents. In addition to the Zener's current limit impacting this device's 500 mA max rating, the clamping diode also has a peak energy limit as well. This energy limit was measured using a rectangular pulse and then translated to an exponential equivalent using the 2:1 relationship between the L/R time constant of an exponential pulse and the pulse width of a rectangular pulse having equal energy content. These L/R time constant limits in ms appear along the V_Z versus I_Z curve for the various values of I_Z at which the Pd lines intersect the V_{CC} limit. The L/R time constant for a given load should not exceed these limits at their respective currents. Precise L/R limits on Zener energy at intermediate current levels can be obtained from Figure 11.

Designing with this Data Sheet

1. Determine the maximum inductive load current (at max V_{CC} , min coil resistance and usually minimum temperature) that the MDC3105 will have to drive and make sure it is less than the max rated current.
2. For pulsed operation, use the Transient Thermal Response of Figure 12 and the instructions with it to determine the maximum limit on transistor power dissipation for the desired duty cycle and temperature range.
3. Use Figures 10 and 11 with the SOA notes above to insure that instantaneous operation does not push the device beyond the limits of the SOA plot.
4. While keeping any $V_{O(sat)}$ requirements in mind, determine the max input current needed to achieve that output current from Figures 2 and 6.
5. For levels of input current below 100 μA , use the input threshold curves of Figure 4 to verify that there will be adequate input current available to turn on the MDC3105 at all temperatures.
6. For levels of input current above 100 μA , enter Figure 3 using that max input current and determine the input voltage required to drive the MDC3105 from the solid V_{in} versus I_{in} line. Select a suitable drive source family from those whose dotted lines cross the solid input characteristic line to the right of the I_{in} , V_{in} point.
7. Using the max output current calculated in step 1, check Figure 7 to insure that the range of Zener clamp voltage over temperature will satisfy all system and EMI requirements.
8. Using Figures 8 and 9, insure that “OFF” state leakage over temperature and voltage extremes does not violate any system requirements.
9. Review circuit operation and insure none of the device max ratings are being exceeded.

APPLICATIONS DIAGRAMS

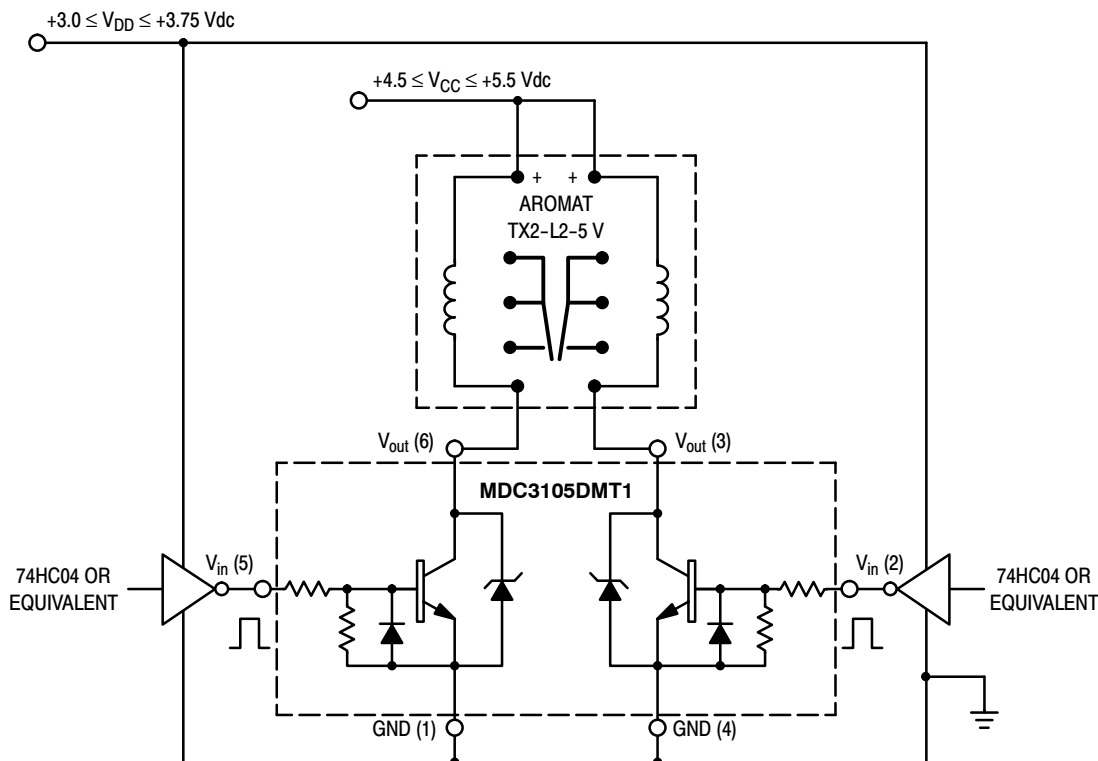


Figure 13. A 200 mW, 5.0 V Dual Coil Latching Relay Application with 3.0 V-HCMOS Level Translating Interface

Max Continuous Current Calculation

for TX2-5V Relay, $R_1 = 178 \Omega$ Nominal @ $R_A = 25^\circ\text{C}$

Assuming $\pm 10\%$ Make Tolerance,

$R_1 = 178 \Omega * 0.9 = 160 \Omega$ Min @ $T_A = 25^\circ\text{C}$

T_C for Annealed Copper Wire is $0.4\%/^\circ\text{C}$

$R_1 = 160 \Omega * [1 + (0.004) * (-40^\circ - 25^\circ)] = 118 \Omega$ Min @ -40°C

$I_O \text{ Max} = (5.5 \text{ V Max} - 0.25 \text{ V}) / 118 \Omega = 45 \text{ mA}$

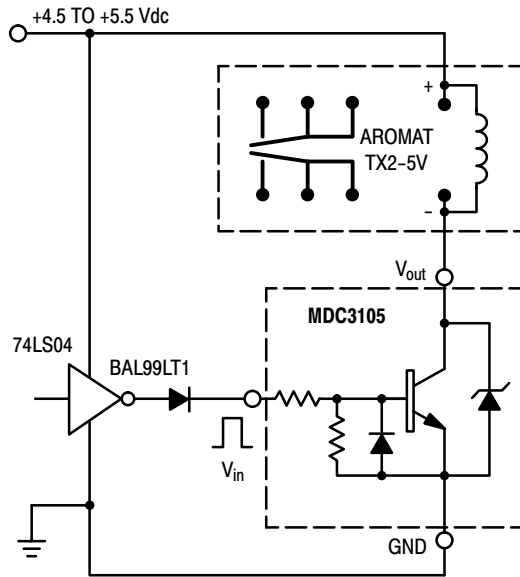


Figure 14. A 140 mW, 5.0 V Relay with TTL Interface

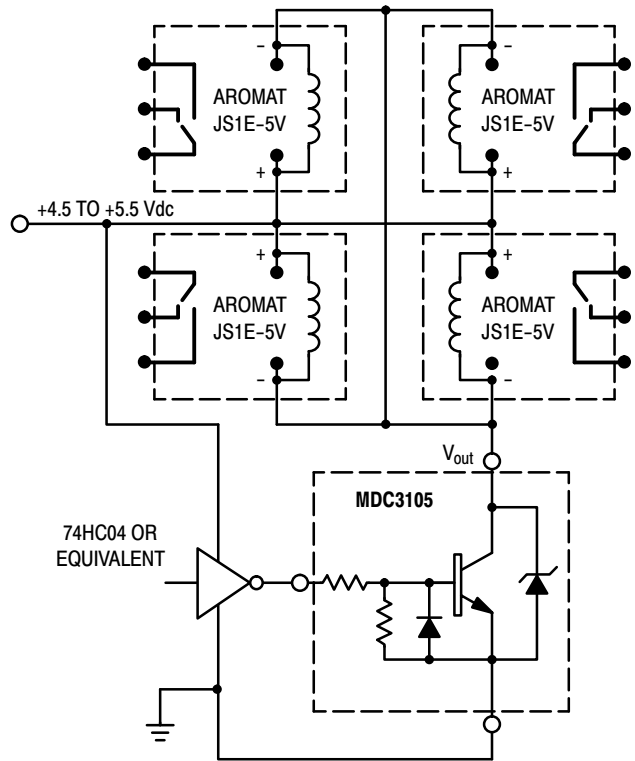


Figure 15. A Quad 5.0 V, 360 mW Coil Relay Bank

TYPICAL OPERATING WAVEFORMS

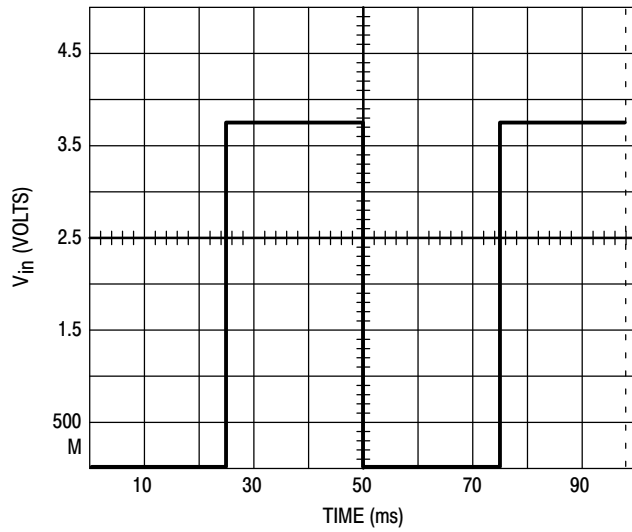


Figure 16. 20 Hz Square Wave Input

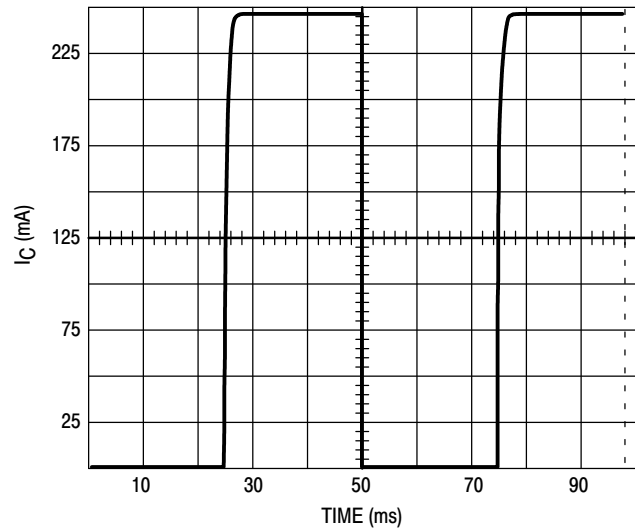


Figure 17. 20 Hz Square Wave Response

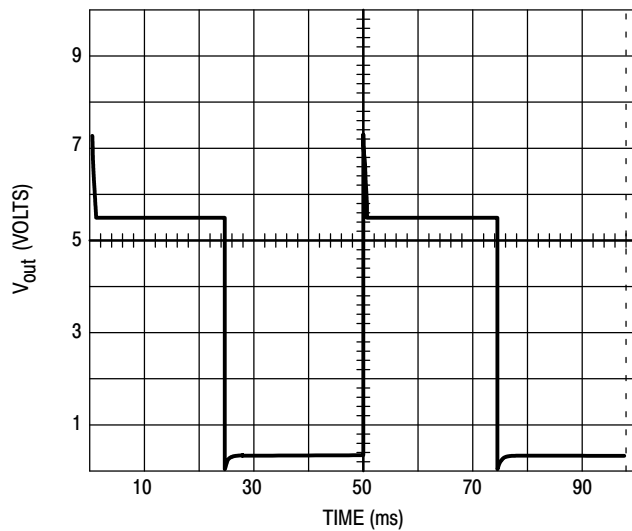


Figure 18. 20 Hz Square Wave Response

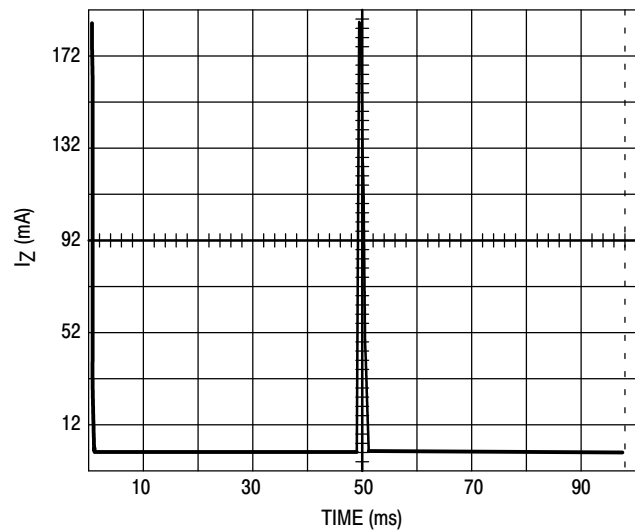
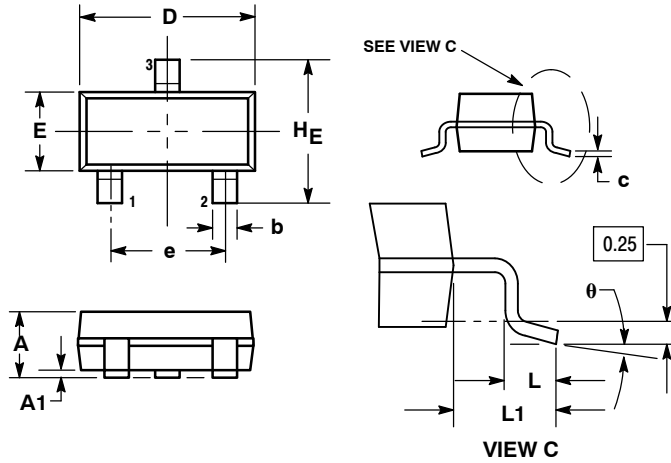


Figure 19. 20 Hz Square Wave Response

MDC3105

PACKAGE DIMENSIONS

SOT-23 (TO-236)
CASE 318-08
ISSUE AN



NOTES:

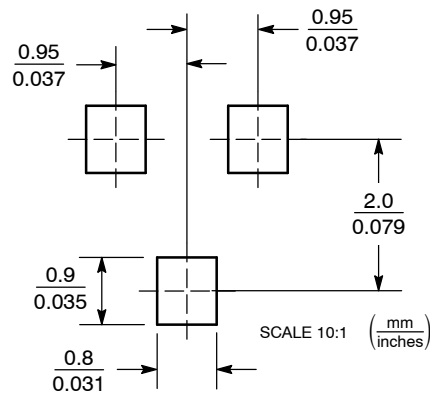
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2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
H _E	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6:

- PIN 1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*

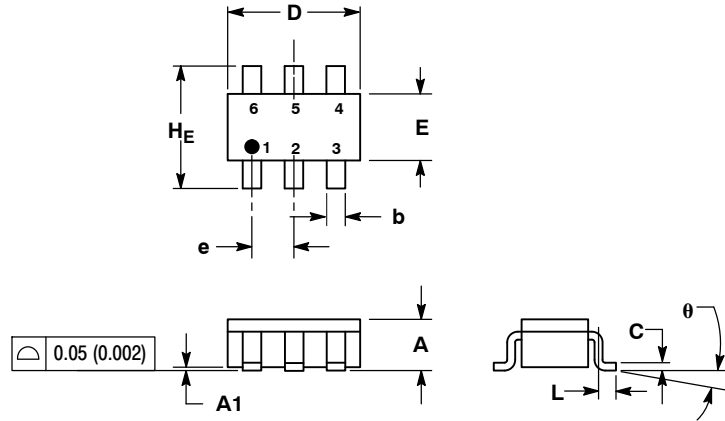


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MDC3105

PACKAGE DIMENSIONS

SC-74 CASE 318F-05 ISSUE M



NOTES:

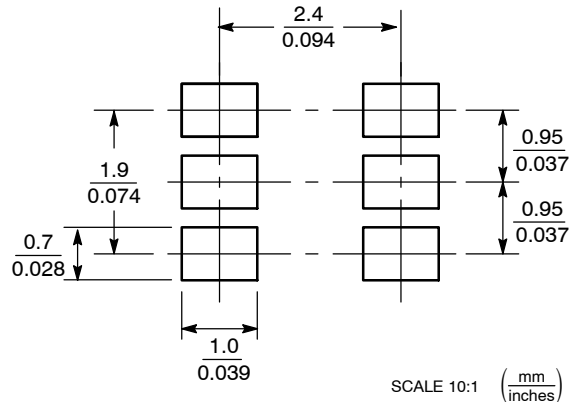
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4. 318F-01, -02, -03, -04 OBSOLETE. NEW STANDARD 318F-05.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
c	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	0.85	0.95	1.05	0.034	0.037	0.041
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.75	3.00	0.099	0.108	0.118
θ	0°	—	10°	0°	—	10°

STYLE 8:

- PIN 1. EMITTER 1
- BASE 2
- COLLECTOR 2
- EMITTER 2
- BASE 1
- COLLECTOR 1

SOLDERING FOOTPRINT*

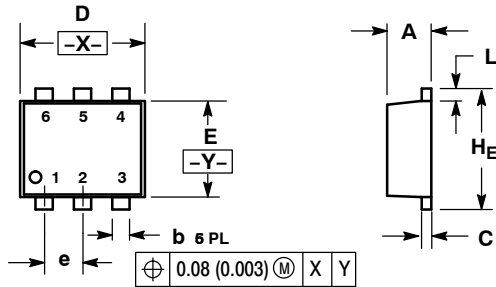


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MDC3105

PACKAGE DIMENSIONS

SOT-563, 6 LEAD CASE 463A-01 ISSUE F



NOTES:

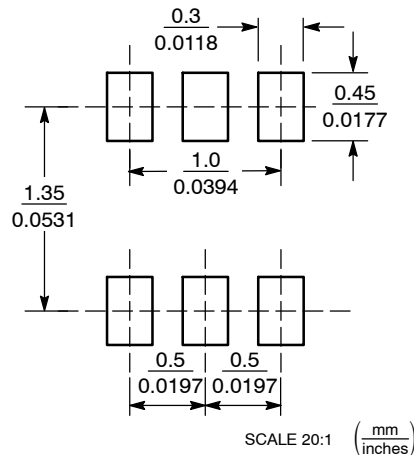
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2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.50	0.55	0.60	0.020	0.021	0.023
b	0.17	0.22	0.27	0.007	0.009	0.011
C	0.08	0.12	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.062	0.066
E	1.10	1.20	1.30	0.043	0.047	0.051
e	0.5 BSC			0.02 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
H _E	1.50	1.60	1.70	0.059	0.062	0.066

STYLE 4:

- PIN 1: COLLECTOR
2: COLLECTOR
3: BASE
4: EMITTER
5: COLLECTOR
6: COLLECTOR

SOLDERING FOOTPRINT*



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